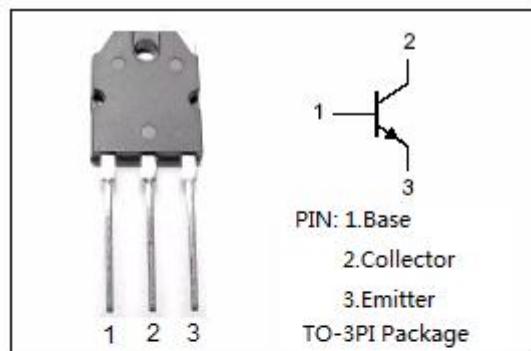


**DESCRIPTION**

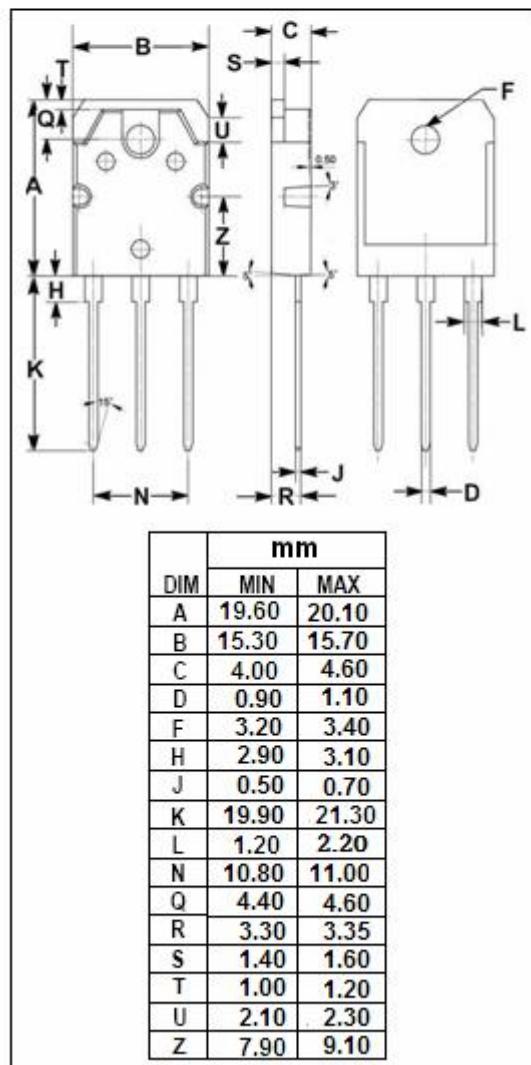
- Collector-Emitter Breakdown Voltage-  
:  $V_{(BR)CEO} = 50V$  (Min)
- Low Collector-Emitter Saturation Voltage-  
:  $V_{CE(sat)} = 0.4V$  (Max)@ $I_c = 4A$
- High Collector Power Dissipation  
:  $P_c = 60W$  @ $T_c = 25^\circ C$
- Complement to Type 2SB754

**APPLICATIONS**

- High current switching applications
- Power amplifier applications

**ABSOLUTE MAXIMUM RATINGS( $T_a=25^\circ C$ )**

SYMBOL	PARAMETER	VALUE	UNIT
$V_{CBO}$	Collector-Base Voltage	50	V
$V_{CEO}$	Collector-Emitter Voltage	50	V
$V_{EBO}$	Emitter-Base Voltage	5	V
$I_c$	Collector Current-Continuous	7	A
$I_e$	Emitter Current-Continuous	7	A
$P_c$	Collector Power Dissipation @ $T_a=25^\circ C$	2.5	W
	Collector Power Dissipation @ $T_c=25^\circ C$	60	
$T_j$	Junction Temperature	150	°C
$T_{stg}$	Storage Temperature Range	-55~150	°C



# SPTECH Product Specification

## SPTECH Silicon NPN Power Transistor

**2SD844**

### ELECTRICAL CHARACTERISTICS

T<sub>c</sub>=25°C unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>(BR)CEO</sub>	Collector-Emitter Breakdown Voltage	I <sub>C</sub> = 10mA ; I <sub>B</sub> = 0	50			V
V <sub>(BR)EBO</sub>	Emitter-Base Breakdown Voltage	I <sub>E</sub> = 1mA ; I <sub>C</sub> = 0	5			V
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage	I <sub>C</sub> = 4A; I <sub>B</sub> = 0.4A		0.2	0.4	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage	I <sub>C</sub> = 4A ; V <sub>CE</sub> = 1V		0.9	1.2	V
I <sub>CB0</sub>	Collector Cutoff Current	V <sub>CB</sub> = 50V ; I <sub>E</sub> = 0			10	µ A
I <sub>EB0</sub>	Emitter Cutoff Current	V <sub>EB</sub> = 5V ; I <sub>C</sub> = 0			10	µ A
h <sub>FE-1</sub>	DC Current Gain	I <sub>C</sub> = 1A ; V <sub>CE</sub> = 1V	70		240	
h <sub>FE-2</sub>	DC Current Gain	I <sub>C</sub> = 4A ; V <sub>CE</sub> = 1V	30			
f <sub>T</sub>	Current-Gain—Bandwidth Product	I <sub>C</sub> = 1A; V <sub>CE</sub> = 5V		15		MHz
C <sub>OB</sub>	Output Capacitance	I <sub>E</sub> = 0; V <sub>CB</sub> = 10V; f <sub>test</sub> = 1.0MHz		250		pF

### ◆ h<sub>FE-1</sub> Classifications

O	Y
70-140	120-240

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